NSN 5961-00-851-4755

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-851-4755 **Inclosure Material:** Metal **Overall Length:** 0.546 inches **Overall Diameter:** 1.281 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, collector-to-base, emitter open and 200.0 breakdown voltage, collector-to-emitter, base open and 25.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Mounting hardware included; junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No ----

Fiig:

A110a0